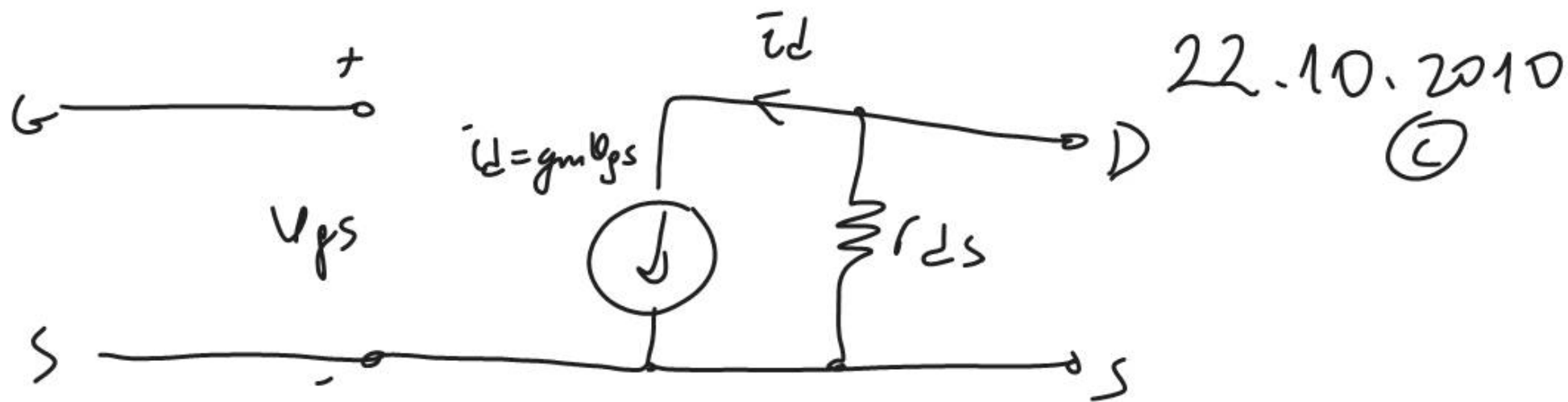
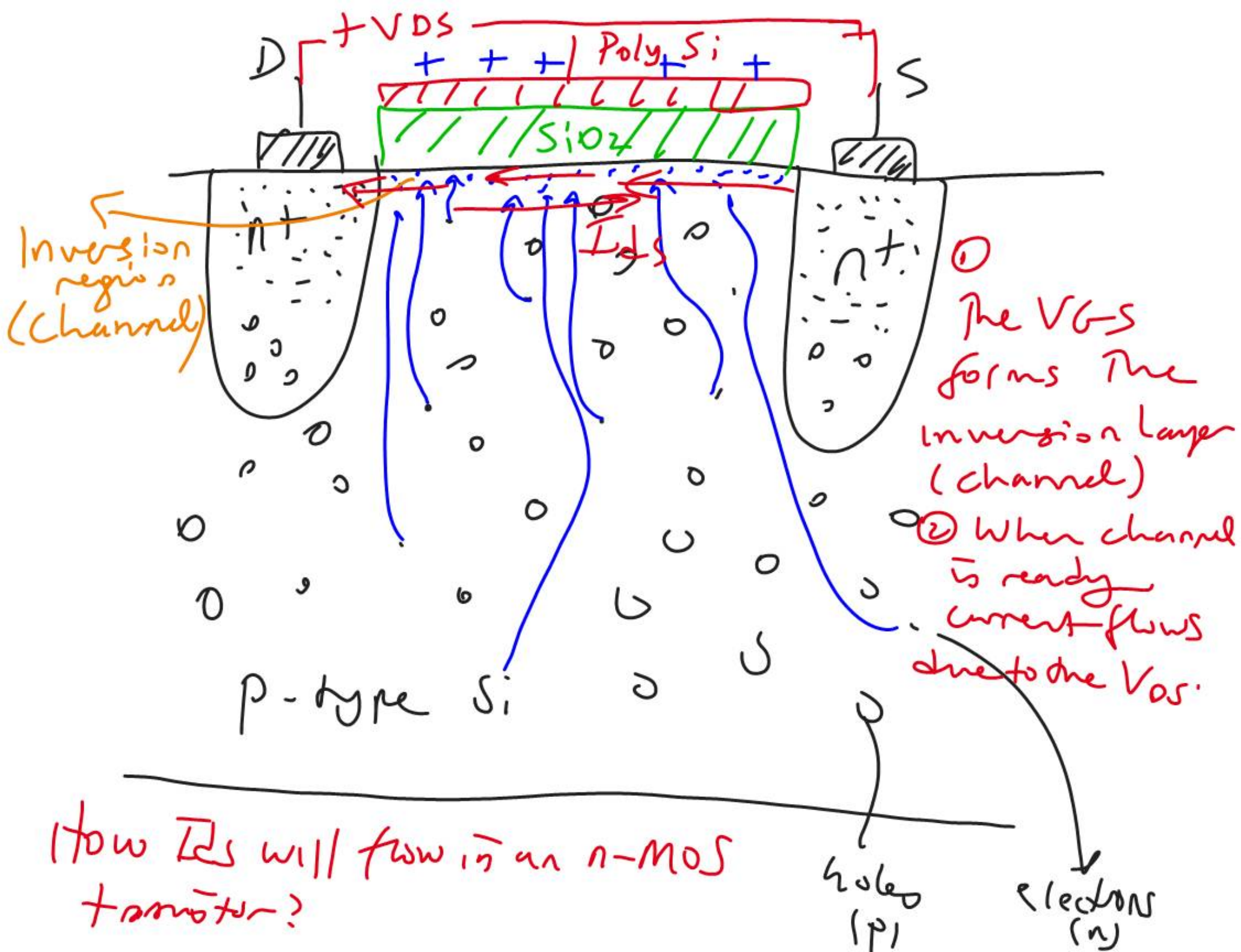




Small signal equivalent of the MOS transistor. It is used when the MOS transistor is used as an amplifier (in linear applications, at medium frequency regions for the particular device).

In Inverters we use the device as a switch. So we apply B/G voltage changes. Operate the MOS in NONLINEAR REGIONS.



Homework #1

Obtain the output characteristics and plot them for an n-channel transistor of

$$L = 200 \text{ nm}$$

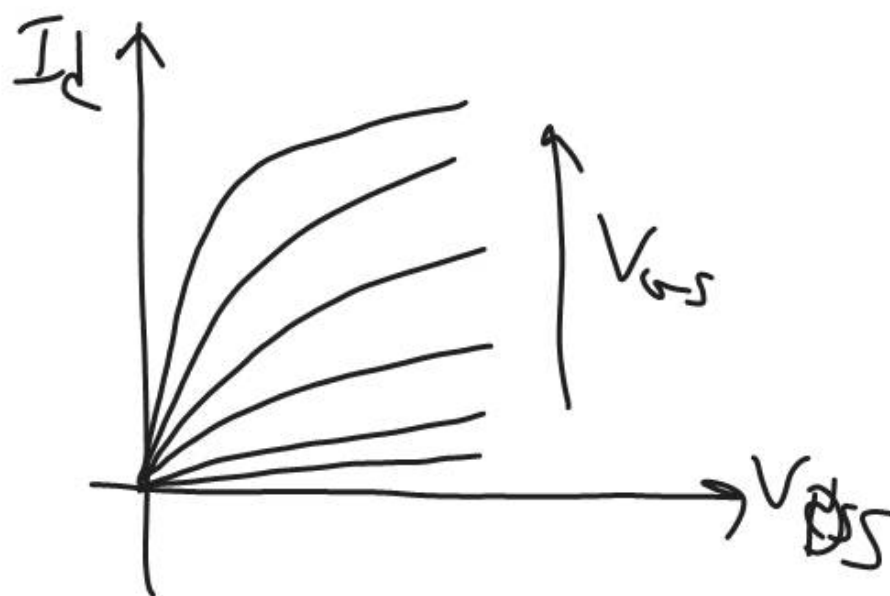
$$\mu = 3600 \text{ cm}^2/\text{V}\cdot\text{s}$$

$$W = 600 \text{ nm}$$

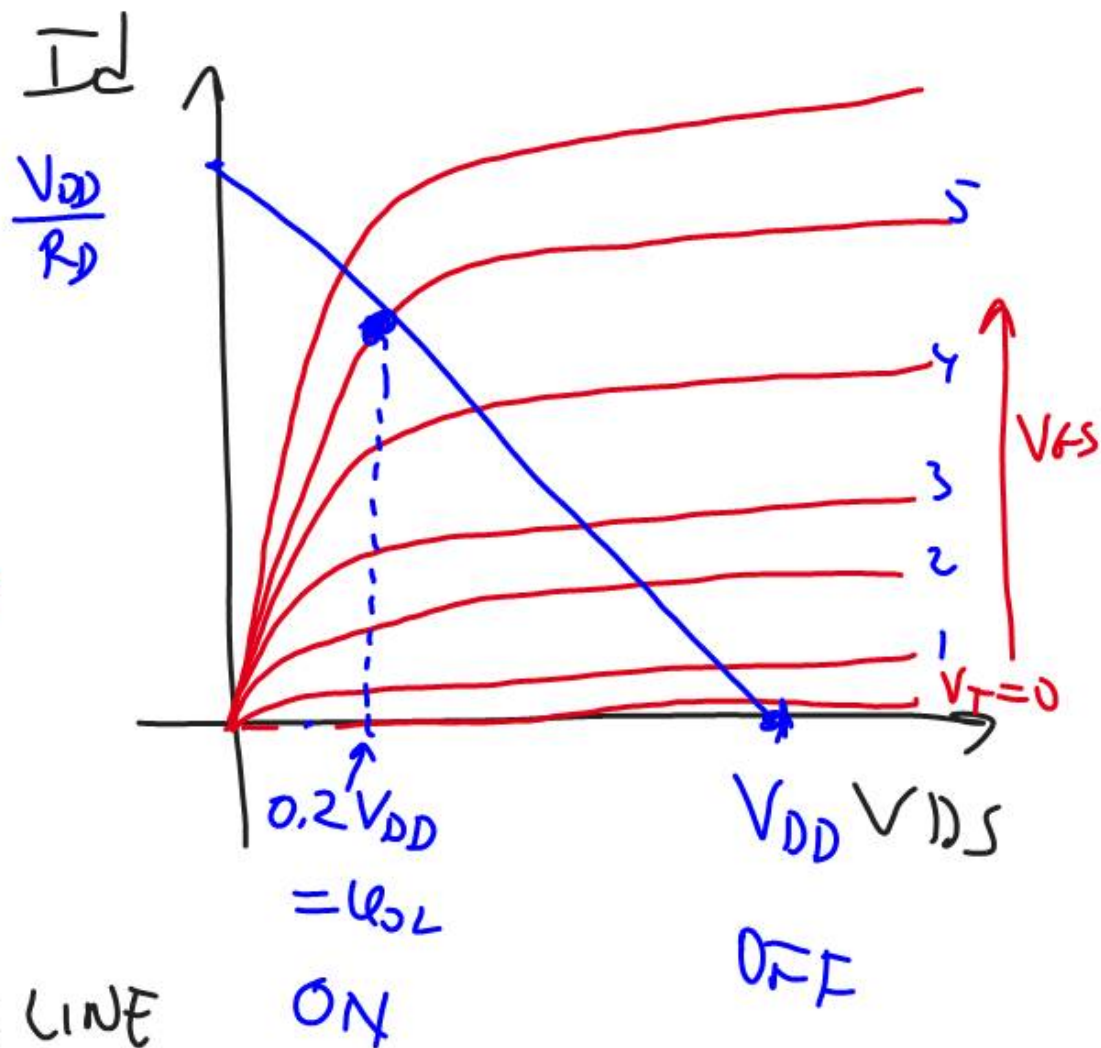
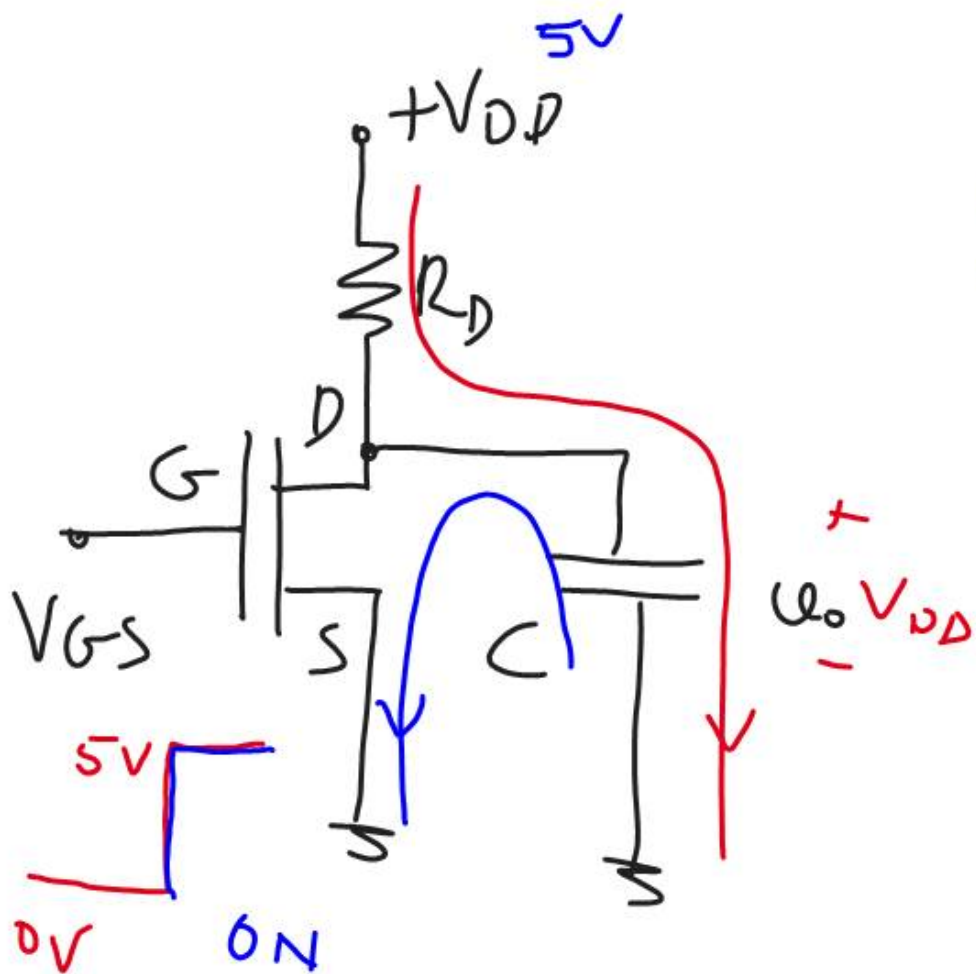
$$\epsilon_r = 12 \quad (\epsilon = \epsilon_r \cdot \epsilon_0)$$

$$t_{ox} = 150 \text{ \AA}$$

USING MATLAB



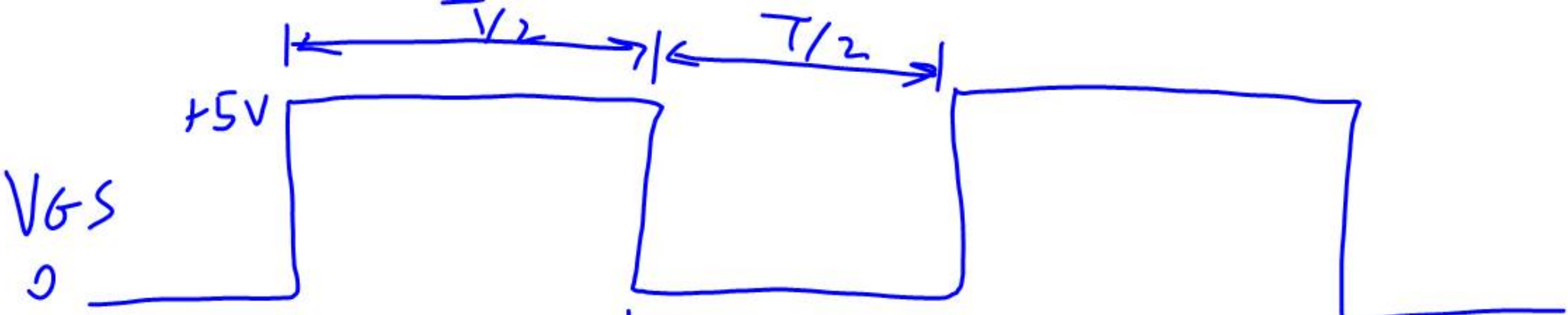
THE BASIC INVERTER



Static

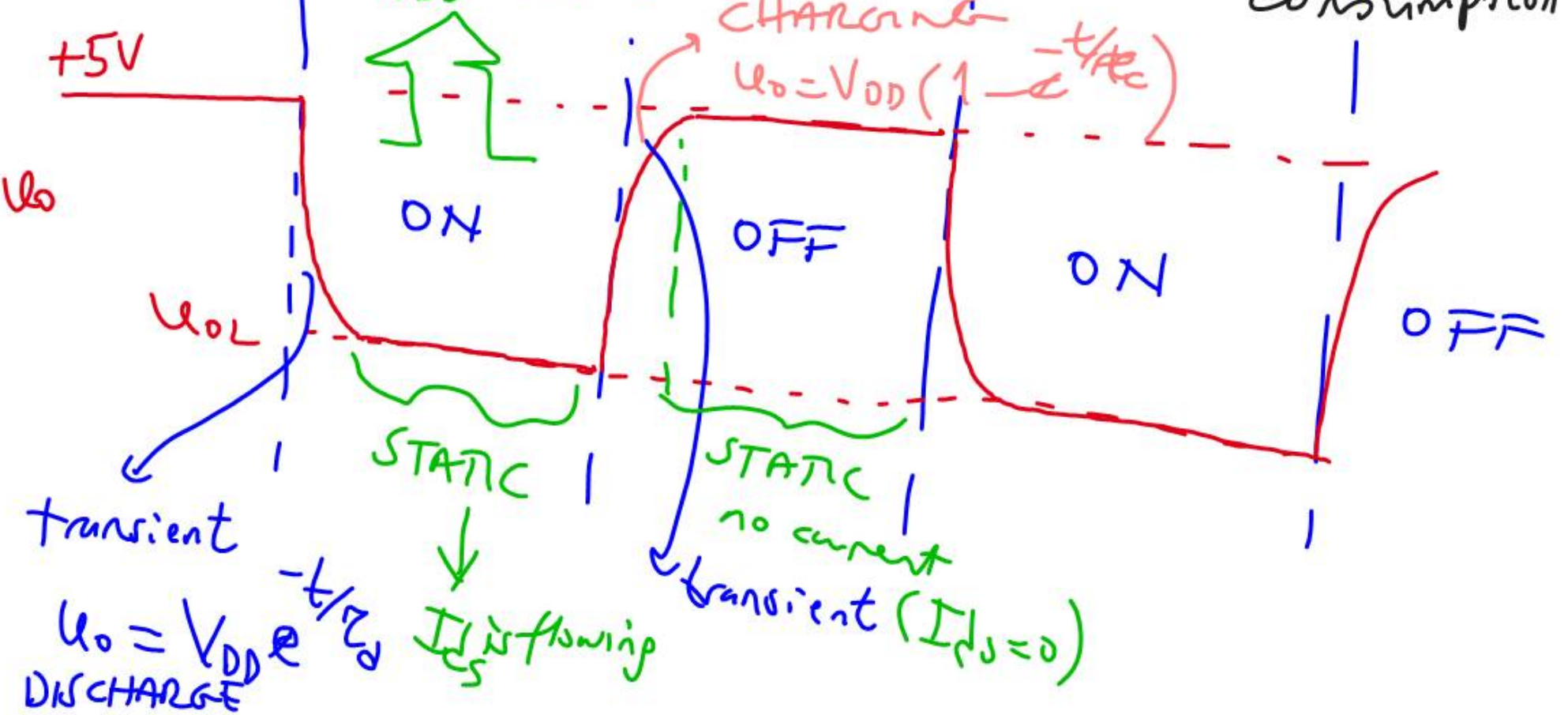
$$V_{DD} - I_D R_D - V_{DS} = 0 \quad \text{LOAD LINE}$$

$$I_D = 0 \quad V_{DS} = V_{DD} \quad \text{when } V_{DS} = 0 \quad I_D = \frac{V_{DD}}{R_D}$$



A current path is formed between V_{DD} and GND.

Problem 1!
Static Power Consumption!



$$\tau_c = R_d \cdot C$$

$$\tau_d = R_{ch} \cdot C$$



Channel resistance
of the MOS
transistor when it is
turned-on

When $v_{OL} \leq 0.2 V_{DD}$

$$v_O = V_{DD} e^{-t/\tau_d}$$

$$0.2 V_{DD} = V_{DD} e^{-t/\tau_d}$$

$$0.2 = e^{-t/\tau_d}$$

$$-\frac{t}{\tau_d} = \ln(0.2)$$

$$-t = \tau_d (-1.6)$$

$$t = 1.6 \tau_d$$

$$t = 1.6 \cdot R_{ch} \cdot C$$

Capacitor charging:

$$V_o = V_{DD} (1 - e^{-t/\tau_c})$$

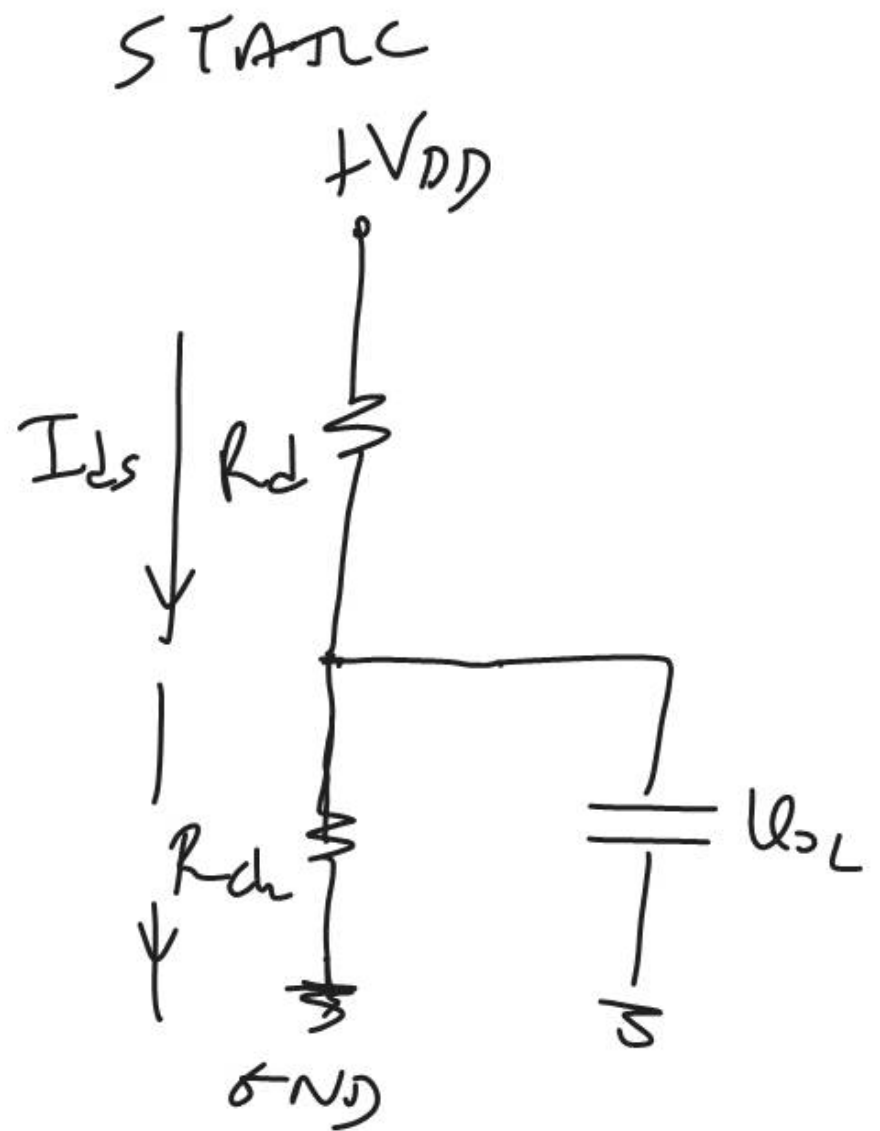
$$V_o = 0.9 V_{DD}$$

$$0.9 V_{DD} = V_{DD} (1 - e^{-t/\tau_c})$$

$$0.1 = -e^{-t/\tau_c}$$

$$t = \tau_c \cdot \ln 0.1$$

$$t = 2.3 R_d \cdot C$$



$$V_oL \cong \frac{V_{DD}}{R_d + R_{ch}} \cdot R_{ch}$$

When $v_{OL} = 0.2 V_{DD}$

$$0.2 \cancel{V_{DD}} = \frac{\cancel{V_{DD}}}{R_D + R_{ch}} \cdot R_{ch}$$

$$0.2 R_D + 0.2 R_{ch} = R_{ch}$$

$$0.2 R_D = 0.8 R_{ch}$$

$$R_D = \frac{0.8 R_{ch}}{0.2}$$

$$R_D = 4 \cdot R_{ch}$$

$$v_{OL} = 0.1 V_{DD}$$

$\Rightarrow$

$$R_D = \frac{0.4 R_{ch}}{0.1}$$

$$R_D = 9 R_{ch}$$

* Problem 2!